



Pseudocapacitive effect and Li⁺ diffusion coefficient in three-dimensionally ordered macroporous vanadium oxide for energy storage



Zhongqiu Tong^{a,b}, Hongbo Xu^c, Guangqun Liu^d, Jiupeng Zhao^c, Yao Li^{b,*}

^a College of Materials and Metallurgical Engineering, Guizhou Institute of Technology, Guiyang 550003, China

^b Center for Composite Materials and Structure, Harbin Institute of Technology, Harbin 150001, China

^c School of Chemical Engineering and Technology, Harbin Institute of Technology, 150001 Harbin, China

^d College of Science, Guizhou Institute of Technology, Guiyang 550003, China

ARTICLE INFO

Article history:

Received 17 May 2016

Received in revised form 21 May 2016

Accepted 22 May 2016

Available online 24 May 2016

Keywords:

Three-dimensionally ordered macroporous structure

Pseudocapacitive effect

Li-ion diffusion coefficient

High rate capability

Vanadium oxide

ABSTRACT

In order to act as extrinsic pseudocapacitor materials, nanoscale vanadium oxides are required to simultaneously exhibit a capacitance-based high power density and an intercalation-based high energy density. We have fabricated a three-dimensionally ordered macroporous (3DOM) structure with a wall thickness of 14 nm that fulfills the above requirements. The 3DOM vanadium oxide film exhibits high rate performance with 355 F g⁻¹ at 0.5 A g⁻¹ and 125 F g⁻¹ at 15 A g⁻¹. The enhanced pseudocapacitive effect and Li-ion diffusion coefficient based on the 3DOM nanostructure, also contributes to the high rate capability of vanadia, which can be confirmed by cyclic voltammetry and chronoamperometry.

© 2016 Elsevier B.V. All rights reserved.

1. Introduction

Vanadium oxides have been widely studied as electrochemical energy storage materials for supercapacitors and Li-ion batteries [1–7] because of their ability to undergo redox intercalation [6,8–10] and the various available oxidation states of vanadium (V–II) [10]. However, their small Li-ion diffusion coefficient and electrical conductivity [11–15] cause the intercalation process to be slow, seriously limiting their energy storage performance [16]. Nanostructured vanadium oxides can provide shortened Li-ion diffusion distances and increased surface areas, leading to efficient Li-ion intercalation and, therefore, to high energy density [17]. Another significant phenomenon that occurs with nanostructuring is the pseudocapacitive effect, originating from the fast faradaic processes occurring at the materials' surface, which can generate high power density [6,18–20]. Nanostructuring is of special significance for vanadium oxides because they are extrinsic pseudocapacitor materials [1,3,5,6,21–25]. The pseudocapacitance of nanostructured vanadia depends strongly on their contact area with the electrolyte. For example, aerogels exhibit almost perfect capacitive cyclic voltammetry (CV) curves [5], while electrospun nanorods exhibit CV curves with sharp and well-separated redox peaks [2].

Among the various nanostructures available, the three-dimensionally ordered macroporous (3DOM) structure is an important

nanoarchitecture for Li-ion storage materials [26–30]. Its bicontinuous structure provides intercontinuous voids for good electrolyte penetration, and continuous thin walls for effective electron transport and Li-ion intercalation. Typically, 3DOM structures are prepared from face-centered-cubic colloidal crystals. The sphere packing factor of 74% in colloidal crystal produces 3DOM materials with a similar porosity and a high surface area [26]. Furthermore, employing small diameter spheres results in 3DOM materials with thin wall structures that may exhibit pseudocapacitive behavior [1,5,6,21–25].

Herein, we have prepared 3DOM vanadium oxide films by electrodeposition within colloidal crystals. The films exhibit a significantly enhanced rate capability. Besides the typical advantages nanostructuring provides, CV and chronoamperometry have revealed that the observed improved performance is also the result of pseudocapacitive effect and improved Li-ion diffusion coefficient.

2. Experimental

Polystyrene colloidal crystals with a sphere diameter of 165 or 480 nm on indium-doped tin oxide substrates were grown by a controlled vertical drying method [31,32]. Anodic deposition of vanadia within the colloidal crystals was performed at 2 V versus Ag/AgCl from a 1:1 mixture of deionized water and ethanol containing VOSO₄ (0.25 M). After removing the template with toluene and drying at 120 °C for 6 h, 3DOM vanadia films were obtained. The 3DOM vanadia samples obtained from colloidal crystals with sphere diameter values

* Corresponding author.

E-mail address: yaoli@hit.edu.cn (Y. Li).

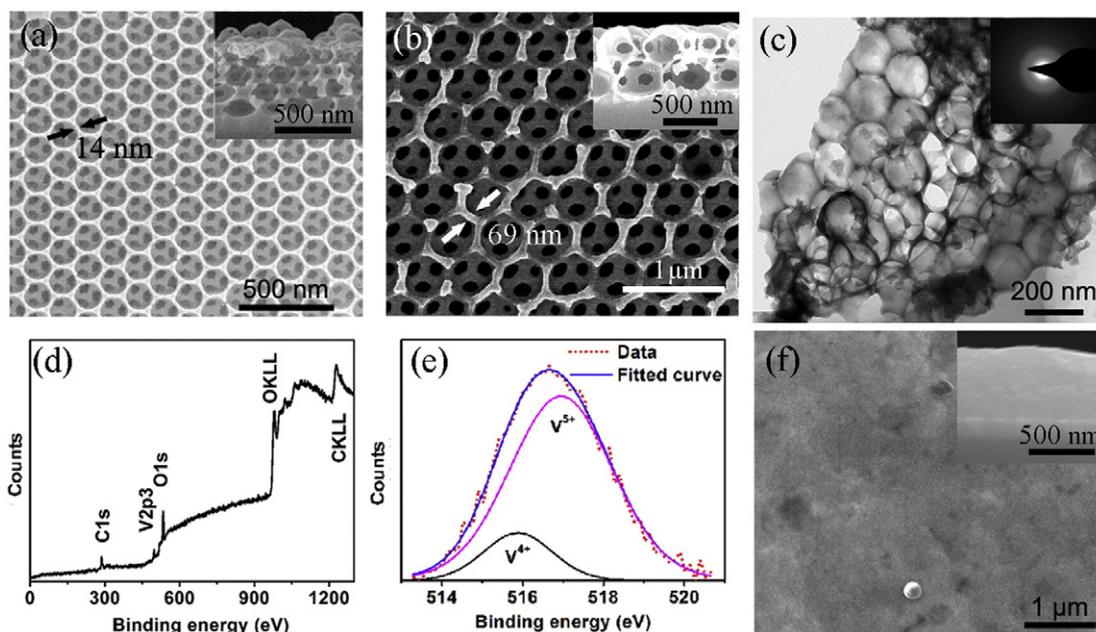


Fig. 1. SEM images of (a) SD-165 nm and (b) SD-480 nm (side view in the inset). TEM image of (c) SD-165 nm (SAED pattern in the inset). (d) Wide-range XPS spectrum, and (e) V_{2p_{3/2}} core peak spectra of SD-165 nm. (f) SEM images of the compact vanadia film (side view in the inset).

of 165 and 480 nm were denoted as SD-165 nm and SD-480 nm, respectively. For comparison, template-free vanadia films were also prepared. The mass loading of SD-165 nm, SD-480 nm, and template-free film were ca. 0.42, 0.55, and 1.57 mg cm⁻², respectively.

Scanning electron microscopy (SEM) images were taken with a FEI Helios Nanolab 600i instrument. Transmission electron microscopy (TEM) images and selected-area electron diffraction (SAED) patterns were recorded on a FEI Tecnai G2F30 instrument. X-ray photoelectron spectroscopy (XPS) analysis was conducted on a PHI 5700 ESCA system. The electrochemical properties were evaluated using a nitrogen-filled three-electrode cell with an electrochemical analyzer (CHI 660D) in 1M LiClO₄-propylene carbonate. A Ag/AgCl electrode was used as the reference electrode and a platinum plate was employed as the counter electrode. A Luggin capillary connected by a salt bridge was used to minimize *iR*-drop errors and to prevent contamination of the cell electrolyte.

3. Results and discussion

Due to the 3D ordered structure of the colloidal crystals, the SD-165 nm and SD-480 nm samples display honeycomb-like structures throughout their entire volume, with nanoscale walls with thickness of about 14 and 69 nm, respectively (Fig. 1a and b). Although powerful ultrasonication during the TEM-sample preparation partly destroyed its structure, the 3DOM nanostructure of SD-165 nm is still clearly observed (Fig. 1c). The presence of only amorphous rings in the SAED

pattern indicates that the as-deposited vanadia is amorphous. The XPS results of the 3DOM vanadia demonstrate its high purity and the presence of a mixture of V⁴⁺ (515.8 eV) and V⁵⁺ (516.9 eV) species (Fig. 1d and e) [33]. The template-free vanadia film exhibits a compact nature (Fig. 1f).

Fig. 2a, b, and c shows, respectively, the galvanostatic discharge/charge performance of SD-165 nm, SD-480 nm, and the compact films at 0.5, 1, 2, 5, 10, and 15 A g⁻¹. These films show featureless and symmetric discharge/charge curves, similar to the curves of other amorphous and nanocrystalline vanadia species [1,6,21–25], indicating that they are suitable materials for supercapacitors [6]. The 3DOM films exhibit a much higher specific capacitance (*C_s*) and rate capability than the compact film, and the 3DOM film with smaller pores (SD-165 nm) shows higher *C_s* values (Fig. 2d). At 0.5 A g⁻¹, the *C_s* value of SD-165 nm was calculated to be 355 F g⁻¹, higher than that of SD-480 nm and the compact film (240 and 187 F g⁻¹, respectively). When the current density reached a high value of 15 A g⁻¹, SD-165 nm still maintained a high *C_s* value of 125 F g⁻¹, whereas values of merely 74 and 22 F g⁻¹ were obtained for SD-480 nm and the compact film, respectively. SD-165 nm exhibits superior charge storage performance compared to many other high-surface-area vanadia, such as nanosheets (314 F g⁻¹ at 0.5 A g⁻¹), interconnected nanoporous networks (304 F g⁻¹ at 0.1 A g⁻¹), and starfruit-like nanoparticles (216 F g⁻¹ at 1 A g⁻¹) [25,34–39].

Besides the common advantages of nanostructures, such as large surface area and short Li-ion diffusion paths [40], the absence of plateau

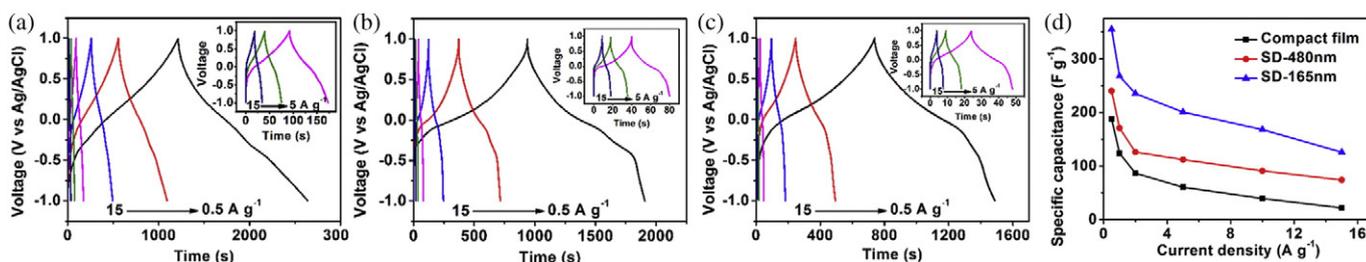


Fig. 2. Galvanostatic charge/discharge curves of (a) SD-165 nm, (b) SD-480 nm, (c) the compact film, and (d) variation of the specific capacitance with the current density for the three vanadia films.

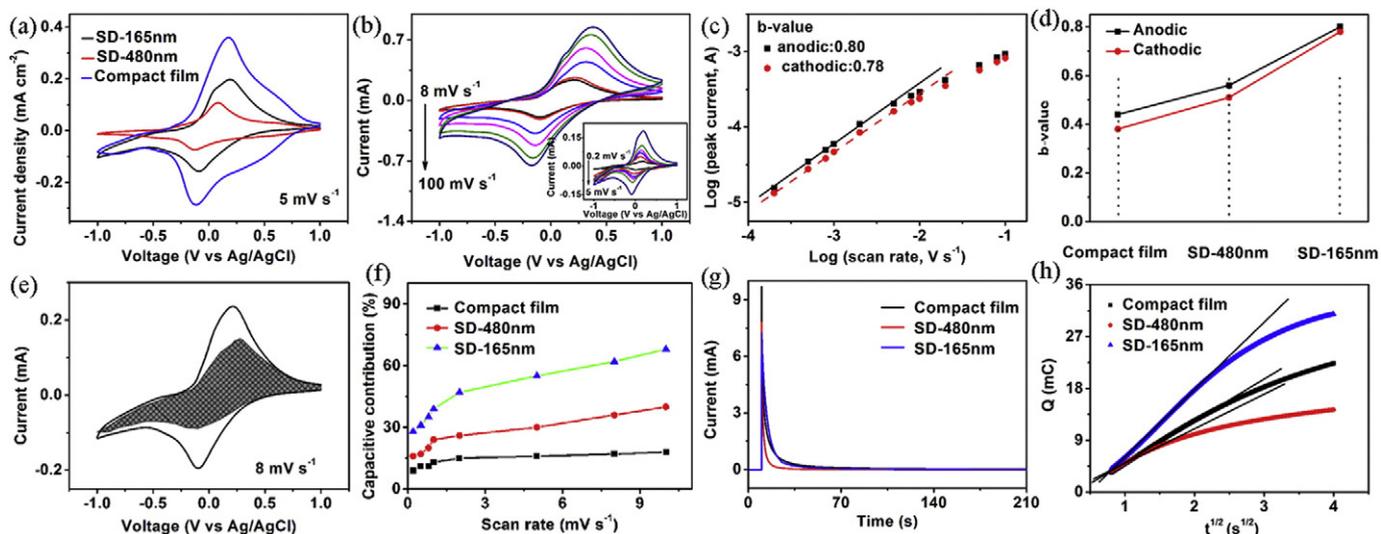


Fig. 3. (a) CV curves of SD-165 nm, SD-480 nm and the compact film at 5 mV s^{-1} . (b) CV curves of SD-165 nm at various scan rates and (c) the corresponding $\log(i)$ vs. $\log(v)$ plots. (d) Summarized b -values for the three vanadia films. (e) Separation of the capacitive (shaded) and diffusion currents in SD-165 nm at 8 mV s^{-1} . (f) Capacitive contribution ratio versus scan rate of the three vanadia films. (g) Chronocoulometric current response curves of the three vanadia films from 1 V to 0 V, and (h) the corresponding Q vs. $t^{1/2}$ plots.

region (indicating phase transformation-based Li-ion intercalation processes) in the charge/discharge curves of SD-165 nm indicates the possible existence of an enhanced pseudocapacitive effect related to the high rate performance observed for this structure [6,18,19]. CV analysis was conducted in order to investigate the influence of the 3DOM structure on the electrochemical behavior of as-deposited vanadia. The similarity among the CV profiles of these three films demonstrates their similar chemical composition (Fig. 3a). Assuming that the redox peak current (i) obeys a power-law relationship to the scan rate (v) leads to the relation $i = av^b$ [18,20], where a and b are adjustable values. When the value of b is 0.5, the current response is diffusion-controlled (intercalative), whereas a value of 1 indicates the current is surface-controlled (capacitive). Fig. 3b and c present the CV behavior of SD-165 nm at different scan rate, from 0.2 to 100 mV s^{-1} , and the corresponding plots of $\log(i)$ vs. $\log(v)$, respectively. Both the anodic and cathodic peaks of SD-165 nm exhibit a good $\log(i)$ – $\log(v)$ linear relation between 0.2 and 5 mV s^{-1} , and the calculated b -values are 0.80 and 0.78, respectively, confirming an enhancement of the pseudocapacitive effect and a high pseudocapacitive energy storage contribution. In contrast, SD-480 nm exhibits values of b of 0.56 and 0.51 for the anodic and cathodic peaks, respectively, and much smaller b -values of 0.44 and 0.38 were found for the compact film (Fig. 3d). The high b -values of SD-165 nm arise from enhanced surface redox reactions and significantly shortened Li-ion diffusion distances, probably even leading to the suppression of phase transformations [6,18,19]. Furthermore, for a specific CV scanning rate, v , the measured current, i , at a fixed potential, V , can be quantitatively separated into capacitive (k_1v) and diffusion-controlled ($k_1v^{1/2}$) responses according to $i(V) = k_1v + k_1v^{1/2}$ [6]. By determining k_1 and k_2 , one can distinguish between Li-ion storage arising from intercalation and energy storage from capacitance. As shown in Fig. 3e, the diffusion-controlled charge of SD-165 nm is mainly generated around the peak voltage at 8 mV s^{-1} . The SD-165 nm sample shows a higher capacitive contribution than that of SD-480 nm and the compact film (Fig. 3f). For instance, 28% of the total charge is capacitive at 0.2 mV s^{-1} in SD-165 nm, whereas the capacitive contribution of SD-480 nm and the compact film is only 16% and 10%, respectively. At 10 mV s^{-1} , the capacitive contribution of SD-165 nm increases up to 68%, much higher than that of SD-480 nm (40%) and the compact film (18%). The high b -values and capacitive contribution of SD-165 nm are related to the film's high rate capability. This nanoscale-dependent electrochemical behavior confirms that vanadia is an extrinsic pseudocapacitor material [2,5,6].

Furthermore, the b -values of the SD-165 nm are far from 1, implying that a Li-ion intercalation also occurs. To further investigate the influence of the 3DOM structure on the Li-ion intercalation kinetics in vanadia, the Li-ion diffusion coefficient (D_{Li}) was evaluated by a chronocoulometric method through the equation: $Q = 2n^{-1/2}FAD_{\text{Li}}^{1/2}C_0t^{1/2} + Q_{\text{dl}} + nFA\Gamma$ [13,31], where Q is the integrated charge, n is the number of electrons transferred in redox reactions, A is the electrode area, D_{Li} is the Li^+ chemical diffusion coefficient, C_0 is the Li^+ surface concentration, Q_{dl} is the double-layer charge, F represent faraday constant, and Γ is the concentration of adsorbed species during the faradic reaction. Fig. 3g and h shows the current response curves of the three films when the voltage was switched from 1 V to 0 V, and the corresponding plots of Q vs. $t^{1/2}$. The data show that the D_{Li} value of SD-165 nm is $2.13 \times 10^{-10} \text{ cm}^2 \text{ s}^{-1}$, higher than that of SD-480 nm ($7.54 \times 10^{-11} \text{ cm}^2 \text{ s}^{-1}$) and the compact film ($8.62 \times 10^{-12} \text{ cm}^2 \text{ s}^{-1}$). The improved D_{Li} value of the SD-165 nm film can be attributed to 3DOM-based structural advantages, that is, to a decreased electrode polarization, rough surface, and three-dimensional electron and Li-ion transport [13,31]. We believe that the improved D_{Li} value also influences positively the Li-ion storage performance of the SD-165 nm film, since a higher D_{Li} value can result in accelerated Li-ion intercalation, thus enabling more vanadium ions to take part in the redox reaction.

4. Conclusions

This study describes how the pseudocapacitive effect and Li^+ diffusion coefficient in 3DOM structures are two important factors that lead to superior energy rate performance of vanadia in an organic electrolyte. Due to the above features, the SD-165 nm vanadia film shows a high rate capability with a C_s of 355 F g^{-1} at 0.5 A g^{-1} and 125 F g^{-1} at 15 A g^{-1} , much higher than that of many other nanostructured vanadia electrodes. The present results are significant toward the applicability of 3DOM structures in energy storage, and the high Li-ion storage performance of this SD-165 nm vanadia film electrode makes it a promising candidate for electrochemical energy storage devices.

Acknowledgment

We thank National Natural Science Foundation of China (Nos. 51572058, 91216123, 51174063, 51502057).

References

- [1] M. Sathiya, A.S. Prakash, K. Ramesha, J.M. Tarascon, A.K. Shukla, V_2O_5 -anchored carbon nanotubes for enhanced electrochemical energy storage, *J. Am. Chem. Soc.* 133 (2011) 16291–16299.
- [2] L. Mai, L. Xu, C. Han, X. Xu, Y. Luo, S. Zhao, Y. Zhao, Electrospun ultralong hierarchical vanadium oxide nanowires with high performance for lithium ion batteries, *Nano Lett.* 10 (2010) 4750–4755.
- [3] D. McNulty, D.N. Buckley, C. O'Dwyer, Comparative electrochemical charge storage properties of bulk and nanoscale vanadium oxide electrodes, *J. Solid State Electrochem.* <http://dx.doi.org/10.1007/s10008-016-3154-2>.
- [4] A. Pan, H. Wu, L. Yu, X.W. Lou, Template-free synthesis of VO_2 hollow microspheres with various interiors and their conversion into V_2O_5 for lithium-ion batteries, *Angew. Chem. Int. Ed.* 125 (2013) 2282–2286.
- [5] E. Armstrong, D. McNulty, H. Geaney, C. O'Dwyer, Electrodeposited structurally stable V_2O_5 inverse opal networks as high performance thin film lithium batteries, *ACS Appl. Mater. Interfaces* 7 (2015) 27006–27015.
- [6] V. Augustyn, P. Simon, B. Dunn, Pseudocapacitive oxide materials for high-rate electrochemical energy storage, *Energy Environ. Sci.* 7 (2014) 1597–1614.
- [7] F. Wang, S. Xiao, Y. Hou, C. Hu, L. Liu, Y. Wu, Electrode materials for aqueous asymmetric supercapacitors, *RSC Adv.* 3 (2013) 13059–13084.
- [8] P. Novák, W. Scheifele, F. Joho, O. Haas, Electrochemical insertion of magnesium into hydrated vanadium bronzes, *J. Electrochem. Soc.* 142 (1995) 2544–2550.
- [9] Q. Wei, J. Liu, W. Feng, J. Sheng, X. Tian, L. He, Q. An, L. Mai, Hydrated vanadium pentoxide with superior sodium storage capacity, *J. Mater. Chem. A* 3 (2015) 8070–8075.
- [10] Z. Tong, N. Li, H. Lv, Y. Tian, H. Qu, X. Zhang, J. Zhao, Y. Li, Annealing synthesis of coralline V_2O_5 nanorod architecture for multicolor energy-efficient electrochromic device, *Sol. Energy Mater. Sol. Cells* 146 (2016) 135–143.
- [11] S. Yang, Y. Gong, Z. Liu, L. Zhan, D.P. Hashim, L. Ma, R. Vajtai, P.M. Ajayan, Bottom-up approach toward single-crystalline VO_2 -graphene ribbons as cathodes for ultrafast lithium storage, *Nano Lett.* 13 (2013) 1596–1601.
- [12] Z. Tong, H. Lv, X. Zhang, H. Yang, Y. Tian, N. Li, J. Zhao, Y. Li, Novel morphology changes from 3D ordered macroporous structure to V_2O_5 nanofiber grassland and its application in electrochromism, *Sci. Rep.* 5 (2015) 16864.
- [13] Z. Tong, J. Hao, K. Zhang, J. Zhao, B. Su, Y. Li, Improved electrochromic performance and lithium diffusion coefficient in three-dimensionally ordered macroporous V_2O_5 films, *J. Mater. Chem. C* 2 (2014) 3651–3658.
- [14] G. Stefanovich, A. Pergament, D. Stefanovich, Electrical switching and Mott transition in VO_2 , *J. Phys. Condens. Matter* 12 (2000) 8837–8845.
- [15] C. Sanchez, R. Morineau, J. Livage, Electrical conductivity of amorphous V_2O_5 , *Phys. Status Solidi A* 76 (1983) 661–666.
- [16] M. Benmoussa, E. Ibnouelghazi, A. Bennouna, E.L. Ameziane, Structural, electrical and optical properties of sputtered vanadium pentoxide thin films, *Thin Solid Films* 265 (1995) 22–28.
- [17] P. Poizot, S. Laruelle, S. Grugeon, L. Dupont, J.-M. Tarascon, Nano-sized transition-metal oxides as negative-electrode materials for lithium-ion batteries, *Nature* 407 (2000) 496–499.
- [18] P. Simon, Y. Gogotsi, B. Dunn, Where do batteries end and supercapacitors begin? *Science* 343 (2014) 1210–1211.
- [19] T. Brousse, D. Bélanger, J.W. Long, To be or not to be pseudocapacitive? *J. Electrochem. Soc.* 162 (2010) A5185–A5189.
- [20] V. Augustyn, J. Come, M.A. Lowe, J. Kim, P. Taberna, S.H. Tolbert, H.D. Abruña, P. Simon, B. Dunn, High-rate electrochemical energy storage through Li^+ intercalation pseudocapacitance, *Nat. Mater.* 12 (2013) 518–522.
- [21] J. Livage, Sol-gel chemistry and electrochemical properties of vanadium oxide gels, *Solid State Ionics* 86–88 (1996) 935–942.
- [22] Z. Chen, V. Augustyn, X. Jia, Q. Xiao, B. Dunn, Y. Lu, High-performance sodium-ion pseudocapacitors based on hierarchically porous nanowire composites, *ACS Nano* 6 (2012) 4319–4327.
- [23] I.-H. Kim, J.-H. Kim, B.-W. Cho, K.-B. Kim, Pseudocapacitive properties of electrochemically prepared vanadium oxide on carbon nanotube film substrate, *J. Electrochem. Soc.* 153 (2006) A1451–A1458.
- [24] S. Boukhalifa, K. Evanoff, G. Yushin, Atomic layer deposition of vanadium oxide on carbon nanotubes for high-power supercapacitor electrodes, *Energy Environ. Sci.* 5 (2012) 6872–6879.
- [25] G. Wee, H. Soh, Y. Cheah, S. Mhaisalkar, M. Srinivasan, Synthesis and electrochemical properties of electrospun V_2O_5 nanofibers as supercapacitor electrodes, *J. Mater. Chem.* 20 (2010) 6720–6725.
- [26] J.W. Long, B. Dunn, D.R. Rolison, H.S. White, Three-dimensional battery architectures, *Chem. Rev.* 104 (2004) 4463–4492.
- [27] A. Stein, B.E. Wilson, S.G. Rudisill, Design and functionality of colloidal-crystal-templated materials—chemical applications of inverse opals, *Chem. Soc. Rev.* 42 (2013) 2763–2803.
- [28] E.M. Sorensen, S.J. Barry, H. Jung, J.M. Rondinelli, J.T. Vaughey, K.R. Poeppelmeier, Three-dimensionally ordered macroporous $Li_4Ti_5O_{12}$: effect of wall structure on electrochemical properties, *Chem. Mater.* 18 (2006) 482–489.
- [29] H. Yan, S. Sokolov, J.C. Lytle, A. Stein, F. Zhang, W.H. Smyrl, Colloidal-crystal-templated synthesis of ordered macroporous electrode materials for lithium secondary batteries, *J. Electrochem. Soc.* 150 (2003) A1102–A1107.
- [30] H. Kim, M. Kim, J. Cho, Unique structural changes of three-dimensionally ordered macroporous TiO_2 electrode materials during electrochemical cycling, *Adv. Energy Mater.* 2 (2012) 1425–1432.
- [31] Z. Tong, H. Yang, L. Na, H. Qu, X. Zhang, J. Zhao, Y. Li, Versatile displays based on a 3-dimensionally ordered macroporous vanadium oxide film for advanced electrochromic devices, *J. Mater. Chem. C* 3 (2015) 3159–3166.
- [32] Z. Tong, X. Zhang, H. Lv, N. Li, H. Qu, J. Zhao, Y. Li, X. Liu, From amorphous macroporous film to 3D crystalline nanorod architecture: a new approach to obtain high-performance V_2O_5 electrochromism, *Adv. Mater. Interfaces* 2 (2015) 1500230.
- [33] G. Silversmit, D. Depla, H. Poelman, G.B. Marin, R.D. Gryse, Determination of the V2p XPS binding energies for different vanadium oxidation states (V^{5+} to V^{0+}), *J. Electron Spectrosc. Relat. Phenom.* 135 (2004) 167–175.
- [34] J. Zhu, L. Cao, Y. Wu, Y. Gong, Z. Liu, H.E. Hoster, Y. Zhang, S. Zhang, S. Yang, Q. Yan, P.M. Ajayan, R. Vajtai, Building 3D structures of vanadium pentoxide nanosheets and application as electrodes in supercapacitors, *Nano Lett.* 13 (2013) 5408–5413.
- [35] J.S. Bonso, A. Rahy, S.D. Perera, N. Nour, O. Seitz, Y.J. Chabal, K.J. Balkus, J.P. Ferraris, D.J. Yang, Exfoliated graphite nanoplatelets- V_2O_5 nanotube composite electrodes for supercapacitors, *J. Power Sources* 203 (2012) 227–232.
- [36] S.D. Perera, B. Patel, N. Nijem, K. Roodenko, O. Seitz, J.P. Ferraris, Y.J. Chabal, K.J. Balkus Jr., Vanadium oxide nanowire-carbon nanotube binder-free flexible electrodes for supercapacitors, *Adv. Energy Mater.* 1 (2011) 936–945.
- [37] B. Kim, C. Kim, K. Yang, A. Rahy, D.J. Yang, Electrospun vanadium pentoxide/carbon nanofiber composites for supercapacitor electrodes, *Electrochim. Acta* 83 (2012) 335–340.
- [38] B. Saravanakumar, K.K. Purushothaman, G. Muralidharan, Interconnected V_2O_5 nanoporous network for high-performance supercapacitors, *ACS Appl. Mater. Interfaces* 4 (2012) 4484–4490.
- [39] J. Shao, X.Y. Li, Q.T. Qu, H.G. Zheng, One-step hydrothermal synthesis of hexangular starfruit-like vanadium oxide for high power aqueous supercapacitors, *J. Power Sources* 219 (2012) 253–257.
- [40] Z.Q. Tong, Y.Q. Yang, J.Y. Wang, J.P. Zhao, B.-L. Su, Y. Li, Layered polyaniline/graphene film from sandwich-structured polyaniline/graphene/polyaniline nanosheets for high-performance pseudosupercapacitors, *J. Mater. Chem. A* 2 (2014) 4642–4651.